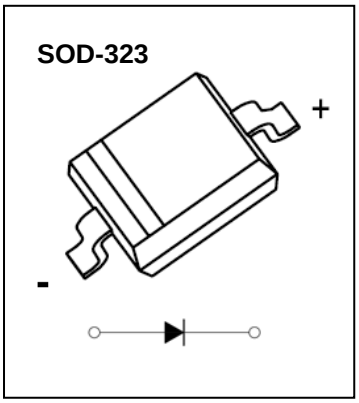
TKRB751V -40

Schottky Barrier Diode

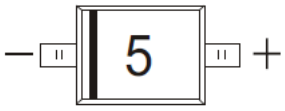
SOD-323 Plastic-Encapsulate Diodes

FEATURES

- Low current rectifier schottky diode
- Low voltage, low inductance
- For power supply



MAKING: 5



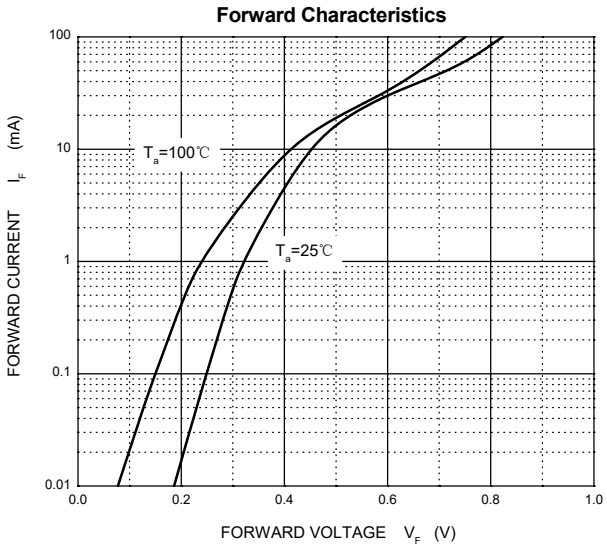
Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25℃

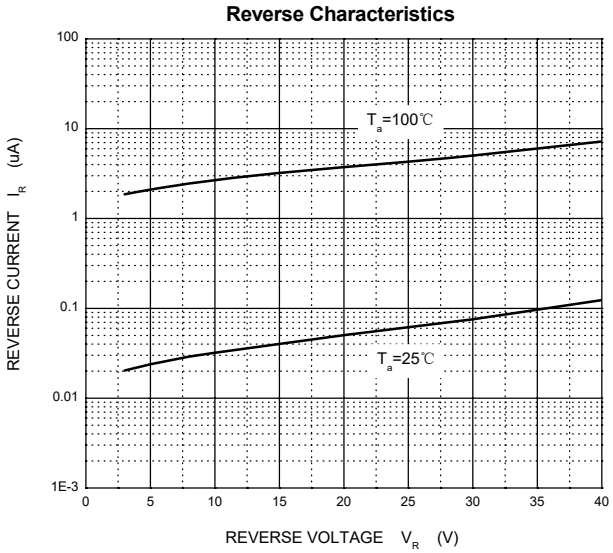
Parameter	Symbol	Limit	Unit
Peak reverse voltage	V_{RM}	40	V
DC reverse voltage	V_R	30	V
Mean rectifying current	I_O	0.03	A
Non-repetitive Peak Forward Surge Current@t=8.3ms	I_{FSM}	0.2	A
Power dissipation	P_D	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	500	℃/W
Operating Junction Temperature Range	T_j	-40 ~ +125	℃
Storage Temperature Range	T_{stg}	-55 ~ +150	℃

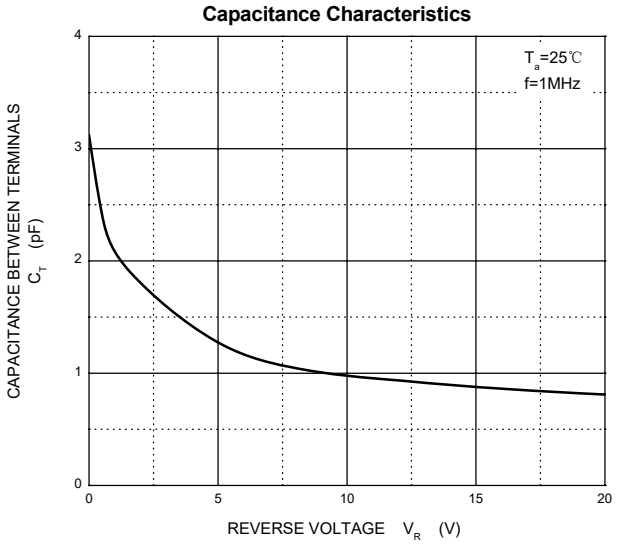
Electrical Ratings @Ta=25℃

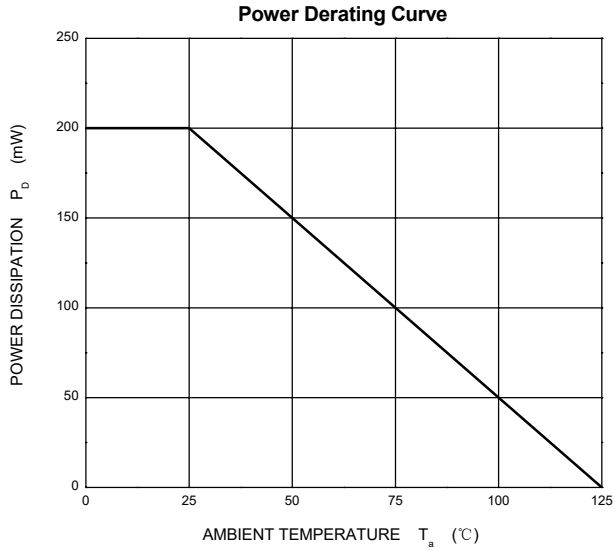
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_F			0.37	V	I_F=1mA
Reverse current	I_R			0.5	μA	V_R=30V
Capacitance between terminals	C_T		2		pF	V_R=1V, f=1MHZ

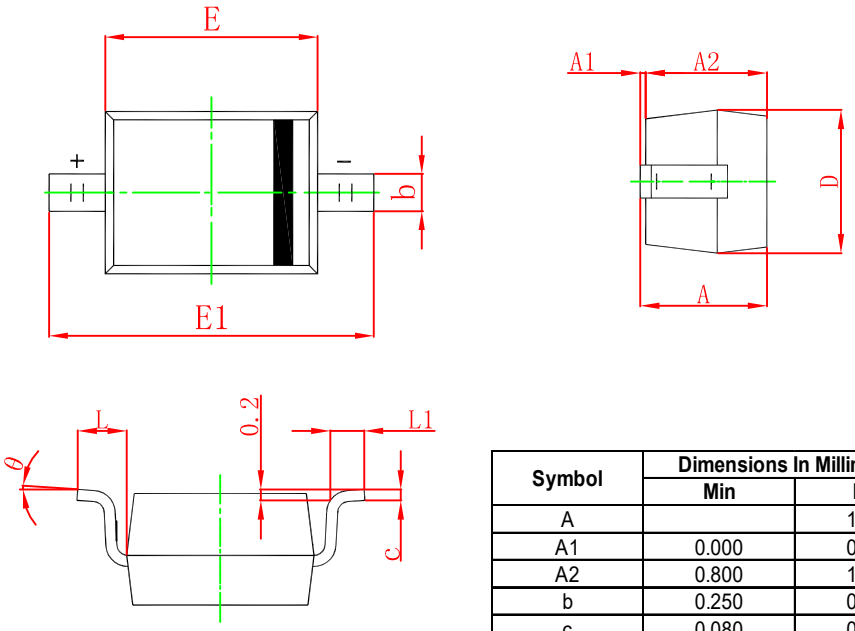
Typical Characteristics





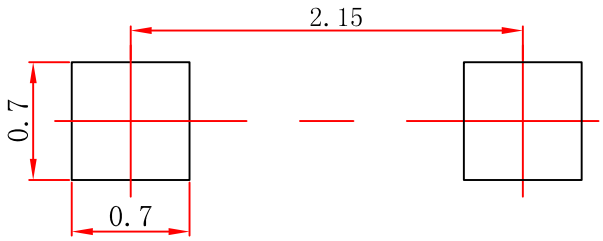






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A		1.100		0.043
A1	0.000	0.100	0.000	0.004
A2	0.800	1.000	0.031	0.039
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.500	2.750	0.098	0.108
L	0.475 REF		0.019 REF	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

SOD-323 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.